阅读申明

- 1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任何异议请及时告之,我们将妥善解决。
- 2.本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
- 3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。
- 4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

- 1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
- 2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
- 3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
- 4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets" .

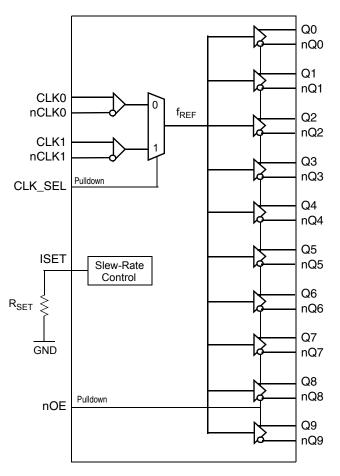


DATA SHEET

General Description

The ICS854110I is a high-performance differential LVDS clock fanout buffer. The device is designed for signal fanout of high-frequency, low phase-noise clock signals. The selected differential input signal is distributed to ten differential LVDS outputs. The ICS854110I is characterized to operate from a 2.5V power supply. Guaranteed output-to-output and part-to-part skew characteristics make the ICS854110I ideal for those clock distribution applications demanding well-defined performance and repeatability. The device offers an output slew rate control with four pre-set output transition times to solve crosstalk and EMI problems in complex board designs. A fail-safe input design forces the outputs to a defined state if differential clock inputs are open or shorted, see Table 3D.

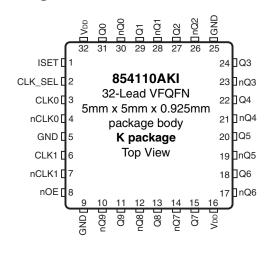
Block Diagram



Features

- Two differential input reference clocks
- Differential pair can accept the following differential input levels: LVPECL, LVDS
- Ten LVDS outputs
- Maximum clock frequency: 200MHz
- Output slew rate control
- · Fail-safe differential inputs
- LVCMOS interface levels for all control inputs
- Output skew: 260ps (maximum), for fastest slew rate setting of 0.650 V/ns
- Part-to-part skew: 1.2ns (maximum)
- Full 2.5V supply voltage
- Lead-free (RoHS 6) 32-Lead VFQFN and 32-Lead LQFP package
- -40°C to 85°C ambient operating temperature

Pin Assignments



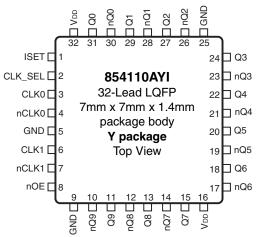


Table 1. Pin Descriptions

Number	Name	Т	уре	Description
1	ISET			An external fixed resistor (RSET) from this pin to ground is needed to provide a reference current for setting the slew rate of the differential outputs Q[0:9], nQ[0:9]. See Table 3C for function.
2	CLK_SEL	Input	Pulldown	Input clock select. See Table 3A for function. LVCMOS/LVTTL interface levels.
3	CLK0	Input		Non-inverting clock/data input 0.
4	nCLK0	Input		Inverting differential clock input 0.
5, 9, 25	GND	Power		Power supply ground.
6	CLK1	Input		Non-inverting clock/data input 1.
7	nCLK1	Input		Inverting differential clock input 1.
8	nOE	Input	Pulldown	Output enable. See Table 3B for function. LVCMOS/LVTTL interface levels.
10, 11	nQ9, Q9	Output		Differential output pair 9. LVDS interface levels.
12, 13	nQ8, Q8	Output		Differential output pair 8. LVDS interface levels.
14, 15	nQ7, Q7	Output		Differential output pair 7. LVDS interface levels.
16, 32	V_{DD}	Power		Power supply pins.
17, 18	nQ6, Q6	Output		Differential output pair 6. LVDS interface levels.
19, 20	nQ5, Q5	Output		Differential output pair 5. LVDS interface levels.
21, 22	nQ4, Q4	Output		Differential output pair 4. LVDS interface levels.
23, 24	nQ3, Q3	Output		Differential output pair 3. LVDS interface levels.
26, 27	nQ2, Q2	Output		Differential output pair 2. LVDS interface levels.
28, 29	nQ1, Q1	Output		Differential output pair 1. LVDS interface levels.
30, 31	nQ0, Q0	Output		Differential output pair 0. LVDS interface levels.

NOTE: Pulldown refers to an internal input resistor. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ

Function Tables

Table 3A. CLK_SEL Configuration Table

Input	
CLK_SEL	Operation
0	CLK0, nCLK0 is the selected reference clock
1	CLK1, nCLK1 is the selected reference clock

NOTE: CLK_SEL is an asynchronous control.

Table 3B. nOE Configuration Table

Input	
nOE	Operation
0	Outputs Qx, nQx are enabled.
1	Outputs Qx, nQx are in high-impedance state.

NOTE: OE is an asynchronous control.

Table 3C. R_{SET} Configuration Table

R _{SET}	
Resistor Size (k Ω)	Typical Output Slew Rate (V/ns)
4	0.650 (fastest)
15	0.170
50	0.150
150	0.115 (slowest)

NOTE: The RSET resistor at the ISET pin allows configuration of the outputs to one of four pre-set output slew rates. A 5% variation of the RSET resistor size will be tolerated.

NOTE: Slew rates are defined as $\pm 100 \text{mV}$ from the center of Q – nQ signal.

Table 3D. Guaranteed Input Fail Safe Operations for CLK0, nCLK0 and CLK1, nCLK1

Input State of Selected Input	Outputs Q[0:9], nQ[0:9]
Logic Low (Selected Input: CLKx = LOW, nCLKx = HIGH)	Logic Low (Qx = LOW, nQx = HIGH)
Logic High (Selected Input: CLKx = HIGH, nCLKx = LOW)	Logic High (Qx = HIGH, nQx = LOW)
Inputs Open (Selected Input: CLKx = open, nCLKx = open)	Logic High (Qx = HIGH, nQx = LOW)
Inputs Shorted (Selected Input: CLKx shorted to nCLKx and tied to V _{DD})	Logic High (Qx = HIGH, nQx = LOW)
Input Shorted (Selected Input: CLKx shorted to nCLKx and floating)	Logic High (Qx = HIGH, nQx = LOW)

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V _{DD}	4.6V
Inputs, V _I	-0.5V to V _{DD} + 0.5V
Outputs, I _O (LVDS) Continuos Current Surge Current	10mA 15mA
Package Thermal Impedance, θ _{JA} 32 Lead VFQFN 32 Lead LQFP	37.0°C/W (0 mps) 65.7°C/W (0 mps)
Storage Temperature, T _{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, V_{DD} = 2.5V ± 5%, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		2.375	2.5	2.625	V
		No Load, R _{SET} not connected			18	mA
I _{DD}	Power Supply Current	All Outputs Loaded, $R_{SET} = 4k\Omega$			86	mA
		No Load, R_{SET} = 4k Ω			30	mA

Table 4B. LVCMOS/LVTTL Input DC Characteristics, V_{DD} = 2.5V \pm 5%, T_A = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage			2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage			-0.3		0.8	V
I _{IH}	Input High Current	CLK_SEL, nOE	$V_{DD} = V_{IN} = 2.625V$			150	μΑ
I _{IL}	Input Low Current	CLK_SEL, nOE	$V_{DD} = 2.625V, V_{IN} = 0V$	-5			μΑ

Table 4C. Differential DC Characteristics, V_{DD} = 2.5V \pm 5%, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{PP}	Peak-to-Peak Input Voltage; NOTE 1		0.15		1.2	V
V _{CMR}	Common Mode Input Voltage; NOTE 1, 2		GND + 0.8		V _{DD} - 0.85	V

NOTE 1: V_{IL} should not be less than -0.3V.

NOTE 2: Common mode input voltage is defined as VIH.

Table 4D. LVDS DC Characteristics, V_{DD} = 2.5V \pm 5%, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{OD}	Differential Output Voltage	$R_{SET} = 4k\Omega$	250		600	mV
ΔV_{OD}	V _{OD} Magnitude Change	$R_{SET} = 4k\Omega$			50	mV
V _{OS}	Offset Voltage	$R_{SET} = 4k\Omega$	1.115		1.430	V
ΔV _{OS}	V _{OS} Magnitude Change	$R_{SET} = 4k\Omega$			50	mV

AC Electrical Characteristics

Table 5. AC Electrical Characteristics, V_{DD} = 2.5V ± 5%, T_A = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
			$R_{SET} = 4k\Omega$			200	MHz
f	Input Frequency		$R_{SET} = 15k\Omega$			30	MHz
f _{REF}	input Freque	ency	$R_{SET} = 50k\Omega$			200 30 20 16 200 30 20 16 200 30 20 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350 0.325 0.250 55 52 52	MHz
			$R_{SET} = 150k\Omega$			16	MHz
			$R_{SET} = 4k\Omega$			200	MHz
f.	Output	Q[9:0], nQ[9:0]	$R_{SET} = 15k\Omega$			200 30 20 16 200 30 20 16 200 30 20 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350	MHz
f _{OUT}	Frequency	વ[૭.૦], તવ[૭.૦]	$R_{SET} = 50k\Omega$			20	MHz
			$R_{SET} = 150k\Omega$			30 20 16 200 30 20 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350 0.325 0.250 55 52 52 52 52 52 53 55 55 55 55 55 55 55 55 55	MHz
t_{JIT}		ve Phase Jitter, RMS; ive Phase Jitter	$R_{SET} = 4k\Omega$, $f_{REF} = 125MHz$, Integration Range: $12kHz - 20MHz$		0.291		ps
			$R_{SET} = 4k\Omega$	3.2	4.0	4.6	ns
	Propagation	CLKx, nCLKx to	$R_{SET} = 15k\Omega$	4.6	5.5	6.3	ns
t _{PD}	Delay; NOTE 1	any Qx, nQx output	$R_{SET} = 50k\Omega$	5.4	6.5	200 30 20 16 200 30 20 16 200 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350 0.325 0.250 55	ns
			$R_{SET} = 150k\Omega$	7.5	8.3		ns
			$R_{SET} = 4k\Omega$		125		ps
<i>t</i> sk(o)	Output Skew	· NOTE 2 2	$R_{SET} = 15k\Omega$		160	425	ps
<i>i</i> 5k(0)	Output Skew	, NOTE 2, 3	$R_{SET} = 50k\Omega$		200	525	ps
			$R_{SET} = 150k\Omega$		240	200 30 20 16 200 30 20 16 200 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350 0.325 0.250 55 52	ps
<i>t</i> sk(p)	Pulse Skew		$R_{SET} = 4k\Omega$		80	185	ps
ισκ(μ)	i dise skew		RSET ≠ 4kΩ			265	ps
			$R_{SET} = 4k\Omega$		600	1200	ps
tsk(pp)	Part-to-Part 9	Skew; NOTE 3, 4	$R_{SET} = 15k\Omega$		825	1500	ps
ισκ(ρρ)	T dit to T dit t	5KGW, 1401L 0, 4	$R_{SET} = 50k\Omega$		975	2100	ps
			$R_{SET} = 150 k\Omega$		1245	200 30 20 16 200 30 20 16 20 16 4.6 6.3 7.7 9.3 260 425 525 550 185 265 1200 1500 2100 1650 1.3 0.350 0.325 0.250 55 52 52	ps
			$R_{SET} = 4k\Omega$	0.450	0.650	1.3	V/ns
tsl(o)	Output Clock	Slow Rato	$R_{SET} = 15k\Omega$	0.110	0.170	0.350	V/ns
131(0)	Output Olook	Cicw Hate	$R_{SET} = 50k\Omega$	0.110	0.150	0.325	V/ns
			$R_{SET} = 150 k\Omega$	0.075	0.115	0.250	V/ns
			$R_{SET} = 4k\Omega$, $f_{REF} \le 200MHz$	45	50	55	%
odc	Output Duty	Cycle; NOTE 5	$R_{SET} = 15k\Omega$, $f_{REF} \le 30MHz$	48	50	52	%
ouc	Sulput Duty	Cyolo, 1401 L 3	$R_{SET} = 50k\Omega$, $f_{REF} \le 20MHz$	48	50	52	%
			$R_{SET} = 150k\Omega$, $f_{REF} \le 16MHz$	48	50	52	%

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
t _R / t _F	Output Rise/ Fall Time; 30% to 70%	$R_{SET} = 4k\Omega$	100	300	500	ps
		$R_{SET} = 15k\Omega$	600	1030	1600	ps
		$R_{SET} = 50k\Omega$	650	1160	1850	ps
		$R_{SET} = 150k\Omega$	800	1540	2200	ps

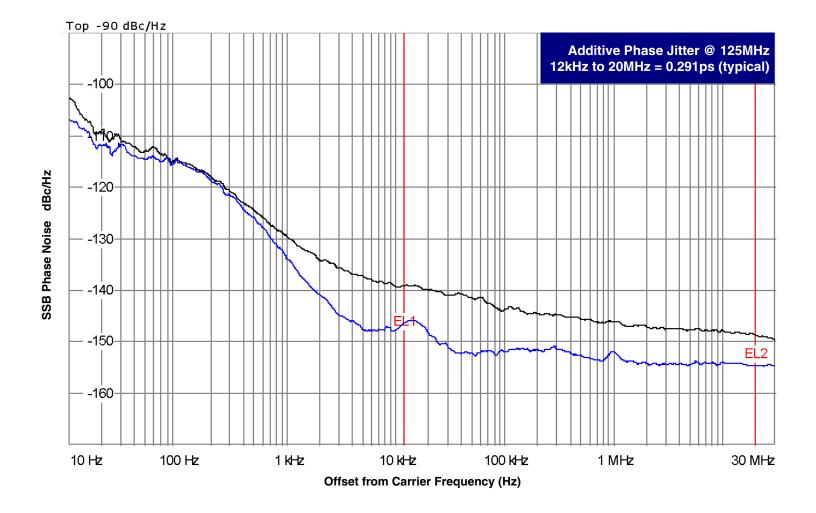
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

- NOTE 1: Measured from the differential input crossing point to the differential output crossing point.
- NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the differential cross points.
- NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
- NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.
- NOTE 5: Input Duty Cycle must be 50%.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a

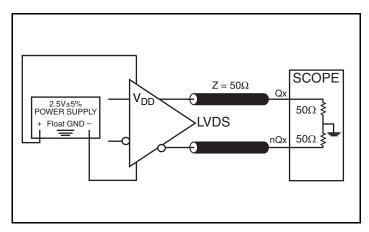
ratio of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



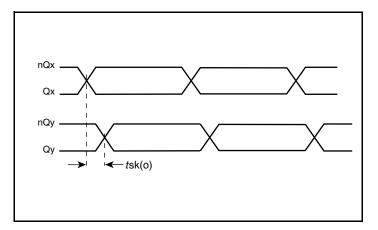
As with most timing specifications, phase noise measurements have issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

The source generator used is, "Rohde & Schwarz SMA 100A Signal Generator into a HP 8133A 3GHz Pulse Generator".

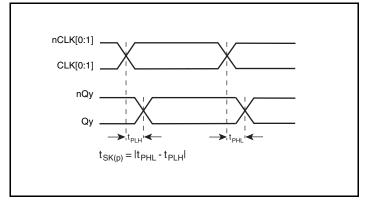
Parameter Measurement Information



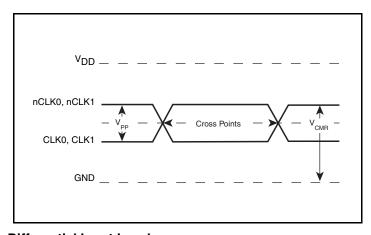
2.5V LVDS Output Load AC Test Circuit



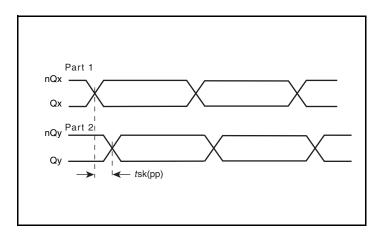
Output Skew



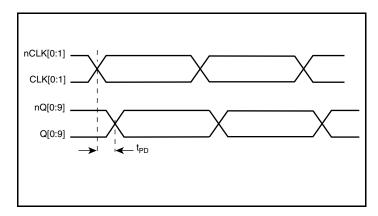
Pulse Skew



Differential Input Level

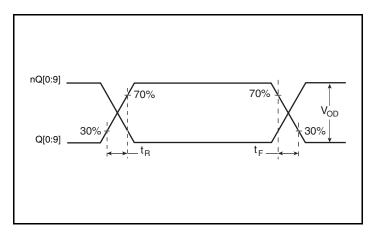


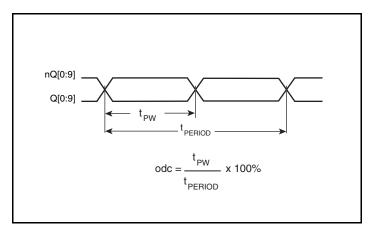
Part-to-Part Skew



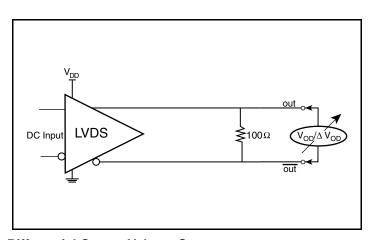
Propagation Delay

Parameter Measurement Information, continued

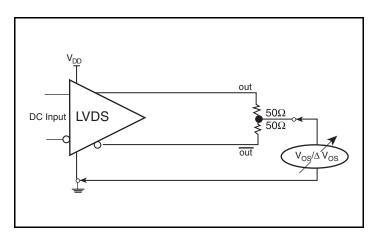




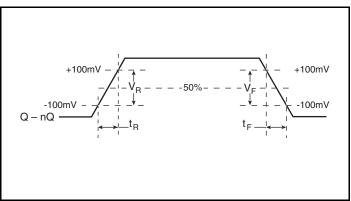
Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period



Differential Output Voltage Setup



Differential Output Slew Rate

Offset Voltage Setup

Applications Information

Wiring the Differential Input to Accept Single-Ended Levels

Figure 1 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{DD}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is 2.5V and $V_{DD} = 3.3V$, R1 and R2 value should be adjusted to set V_{REF} at 1.25V. The values below are for when both the single ended swing and V_{DD} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission

line impedance. For most 50Ω applications, R3 and R4 can be 100Ω . The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however $V_{\rm IL}$ cannot be less than -0.3V and $V_{\rm IH}$ cannot be more than $V_{\rm DD}$ + 0.3V. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

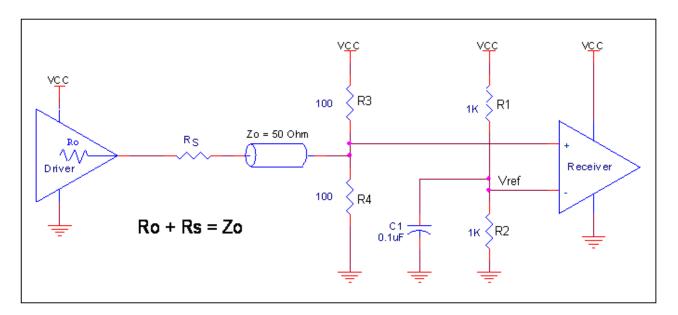


Figure 1. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

Recommendations for Unused Input and Output Pins

Inputs:

CLK/nCLK Inputs

For applications not requiring the use of the differential input, both CLK and nCLK can be left floating. Though not required, but for additional protection, a $1k\Omega$ resistor can be tied from CLK to ground.

LVCMOS Control Pins

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A $1k\Omega$ resistor can be used.

Outputs:

LVDS Outputs

All unused LVDS outputs should be terminated with 100 $\!\Omega$ resistor between the differential pair.

Differential Clock Input Interface

The CLK/nCLK accepts LVPECL, LVDS and other differential signals. Both differential signals must meet the V_{PP} and V_{CMR} input requirements. Figures 2A to 2C show interface examples for the CLK/nCLK input driven by the most common driver types. The input

 $\begin{array}{c}
2.5V \\
\hline
Z_0 = 50\Omega \\
\hline
LVPECL
\end{array}$ $\begin{array}{c}
R_1 \\
50\Omega \\
\hline
\end{array}$ $\begin{array}{c}
R_2 \\
50\Omega \\
\hline
\end{array}$ $\begin{array}{c}
R_3 \\
18\Omega \\
\hline
\end{array}$

Figure 2A. CLK/nCLK Input Driven by a 2.5V LVPECL Driver

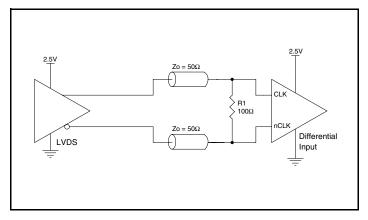


Figure 2C. CLK/nCLK Input Driven by an LVDS Driver

interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

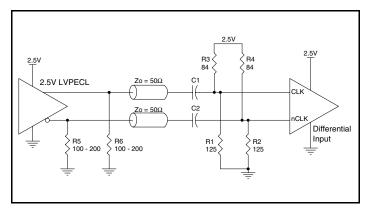


Figure 2B. CLK/nCLK Input Driven by a 2.5V LVPECL Driver with AC Coupler

VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 3*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes". The number of vias (i.e. "heat pipes") are application specific

and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a quideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/ Electrically Enhance Leadframe Base Package, Amkor Technology.

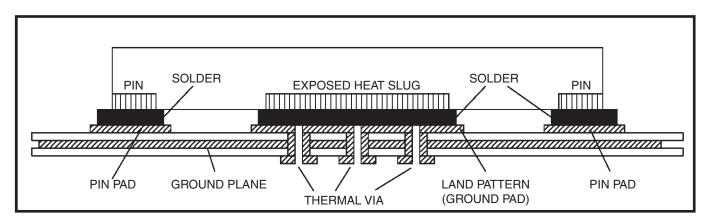


Figure 3. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)

LVDS Driver Termination

A general LVDS interface is shown in Figure 4. Standard termination for LVDS type output structure requires both a 100Ω parallel resistor at the receiver and a 100Ω differential transmission line environment. In order to avoid any transmission line reflection issues, the 100Ω resistor must be placed as close to the receiver as possible. IDT offers a full line of LVDS compliant devices with two types of output structures: current source and voltage source. The standard

termination schematic as shown in Figure 4 can be used with either type of output structure. If using a non-standard termination, it is recommended to contact IDT and confirm if the output is a current source or a voltage source type structure. In addition, since these outputs are LVDS compatible, the amplitude and common mode input range of the input receivers should be verified for compatibility with the output.

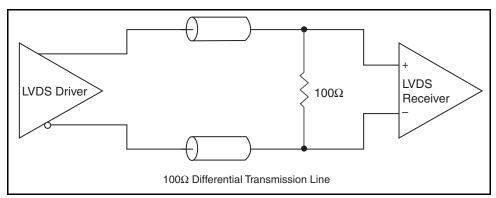


Figure 4. Typical LVDS Driver Termination

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS854110I. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS54110l is the sum of the core power plus the power dissipation in the load(s). The following is the power dissipation for $V_{DD} = 2.5V + 5\% = 2.625V$, which gives worst case results.

Total power dissipation, includes power dissipation on external components.

P_core+load = V_{DD_MAX} * I_{DD_core+load} = 2.625V * 86mA = 225.75mW
 Where:

 $I_{DD\ core+load}$ is the total supply current which includes external components

To calculate the power dissipation on the device alone, Pd_total, and use it for junction temperature calculation, subtract the power dissipation on the external components.

Pd_total = P_core+load - (P_load + P_rset)

Where

P_load is power dissipation on the output loadings P_rset is power dissipation on the R_{SFT}

The load current per output is:

lout = (I_{DD_core+load} - I_{DD_no_load}) / N = (86mA - 18mA) / 10 = 6.8mA

Where:

 $I_{DD_no_load}$ is I_{DD} current at no load condition N is number of outputs

Power Dissipation on output loads

P_load = (lout)^2 * R_load * N = (6.8mA)^2 * 100Ω * 10 = 46.2mW

Power Dissipation on R_{SET}

 P_rset = (Vrset)^2 / R_{SET} = (1V)^2 / 4kΩ = 0.25mW (NOTE: P_rset is small and can be negligible)

Total Power Dissipation on the part excluding the power dissipation on the external components.

```
Pd_total = P_core+load - (P_load + P_rset)
= 225.75mW - (46.2mW + 0.25mW)
= 179.3mW
```

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad, and directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: Tj = θ_{JA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 65.7°C/W per Table 6A below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}\text{C} + 0.179\text{W} * 65.7^{\circ}\text{C/W} = 96.8^{\circ}\text{C}$. This is below the limit of 125°C .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6A. Thermal Resistance θ_{JA} for 32 Lead LQFP, Forced Convection

θ_{JA} by Velocity				
Meters per Second	0	1	2.5	
Multi-Layer PCB, JEDEC Standard Test Boards	65.7°C/W	55.9°C/W	52.4°C/W	

Table 6B. Thermal Resistance θ_{JA} for 32 Lead VFQFN, Forced Convection

θ_{JA} by Velocity				
Meters per Second	0	1	2.5	
Multi-Layer PCB, JEDEC Standard Test Boards	37.0°C/W	32.4°C/W	29.0°C/W	

Reliability Information

Table 7A. θ_{JA} vs. Air Flow Table for a 32-Lead VFQFN

$ heta_{\sf JA}$ vs. Air Flow				
Meters per Second	0	1	2.5	
Multi-Layer PCB, JEDEC Standard Test Boards	37.0°C/W	32.4°C/W	29.0°C/W	

Table 7B. θ_{JA} vs. Air Flow Table for a 32-Lead LQFP

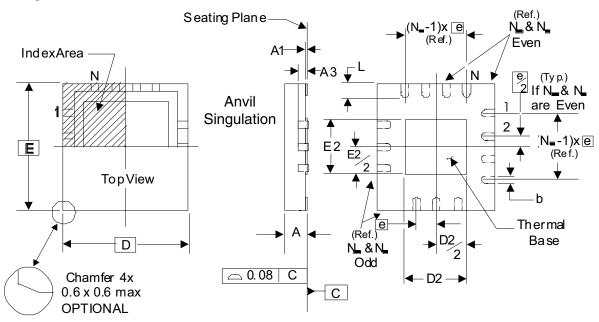
$ heta_{JA}$ vs. Air Flow				
Meters per Second	0	1	2.5	
Multi-Layer PCB, JEDEC Standard Test Boards	65.7°C/W	55.9°C/W	52.4°C/W	

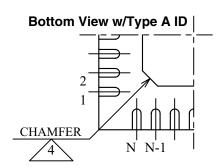
Transistor Count

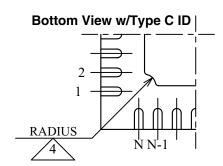
The transistor count for ICS854110I is: 1757

Package Outline and Package Dimensions

Package Outline - K Suffix for 32-Lead VFQFN







There are 2 methods of indicating pin 1 corner at the back of the VFQFN package are:

- 1. Type A: Chamfer on the paddle (near pin 1)
- 2. Type C: Mouse bite on the paddle (near pin 1)

Table 8A. Package Dimensions for 32-Lead VFQFN

IEDE	Variation: VL	JUD-2/-/			
	JEDEC Variation: VHHD-2/-4 All Dimensions in Millimeters				
Symbol	Minimum	Maximum			
N	3	2			
Α	0.80	1.00			
A1	0 0.05				
А3	0.25 Ref.				
b	0.18	0.30			
N _D & N _E		8			
D&E	5.00	Basic			
D2 & E2	3.0	3.3			
е	0.50 Basic				
L	0.30	0.50			

Reference Document: JEDEC Publication 95, MO-220

NOTE: The following package mechanical drawing is a generic drawing that applies to any pin count VFQFN package. This drawing is not intended to convey the actual pin count or pin layout of this device. The pin count and pinout are shown on the front page. The package dimensions are in Table 8A.

Package Outline and Package Dimensions

Package Outline - Y Suffix for 32-Lead LQFP

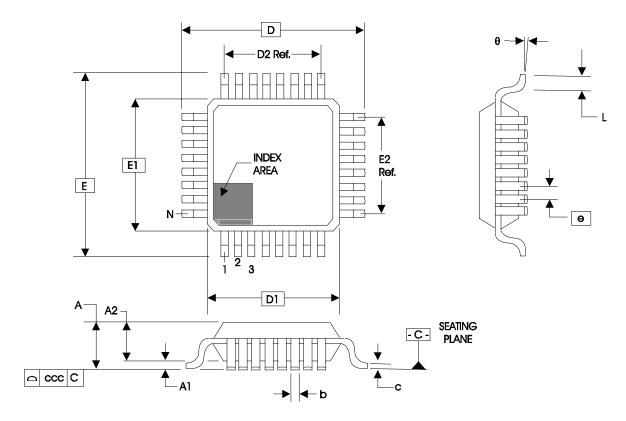


Table 8B. Package Dimensions 32 Lead LQFP

JEDEC Variation: BBA All Dimensions in Millimeters							
Symbol							
N		32					
Α			1.60				
A1	0.05	0.10	0.15				
A2	1.35	1.40	1.45				
b	0.30		0.45				
С	0.09		0.20				
D & E	9.00 Basic						
D1 & E1	7.00 Basic						
е	0.80 Basic						
L	0.45	0.60	0.75				
θ	0°		7°				
ccc			0.10				

Reference Document: JEDEC Publication 95, MS-026

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
854110AKILF	ICS54110AIL	"Lead-Free" 32 Lead VFQFN	Tray	-40°C to 85°C
854110AKILFT	ICS54110AIL	"Lead-Free" 32 Lead VFQFN	2500 Tape & Reel	-40°C to 85°C
854110AYILF	ICS854110AIL	"Lead-Free" 32 Lead LQFP	Tray	-40°C to 85°C
854110AYILFT	ICS854110AIL	"Lead-Free" 32 Lead LQFP	1000 Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial and industrial applications. Any other applications, such as those requiring high reliability or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

Revision History Sheet

Rev	Table	Page	Description of Change	Date
В	T4A	4	Power Supply DC Characteristics Table - added I _{DD} spec of 30mA max.	1/27/11

We've Got Your Timing Solution



6024 Silver Creek Valley Road San Jose, California 95138 ales

800-345-7015 (inside USA) +408-284-8200 (outside USA) Fax: 408-284-2775 www.IDT.com/go/contactIDT Technical Support

netcom@idt.com +480-763-2056

DISCLAIMER Integrated Device Technology, Inc. (IDT) and its subsidiaries reserve the right to modify the products and/or specifications described herein at any time and at IDT's sole discretion. All information in this document, including descriptions of product features and performance, is subject to change without notice. Performance specifications and the operating parameters of the described products are determined in the independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are registered trademarks of IDT. Other trademarks and service marks used herein, including protected names, logos and designs, are the property of IDT or their respective third party owners.